

100V P-Channel Enhancement Mode MOSFET

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Product Summary

BVDSS	RDSON	ID
-100V	750mΩ	-1 A

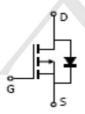
Application

- Load/Power Switching
- Interfacing Switching
- Logic Level Shift

Circuit diagram



Package and Pin Configuration



Marking:

SOT-23



"₽" is TECHPUBLIC LOGO

Absolute Maximum Ratings (T_A=25 ℃ unless otherwise noted)

PARAMETE	SYMBOL	LIMIT	UNITS		
Drain-Source Voltage		V _{DS}	-100		
Gate-Source Voltage		V _{GS}	<u>+</u> 20	\ \ \	
	T _A =25°C		-1	A	
Continuous Drain Current (Note 4)	T _A =70°C		-0.75		
Pulsed Drain Current (Note 1)	I _{DM}	-3.6			
Power Dissipation	T _A =25°C		1.25	W	
	T _A =70°C	P _D	0.8		
Single Pulse Avalanche Energy (Not	Eas	0.2	mJ		
Operating Junction and Storage Te	T _J ,T _{STG}	-55~150	°C		
Typical Thermal resistance - Junction to Ambient (Note 4,5)		Reja	100	°C/W	



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Electrical Characteristics (T_J=25 °C, unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =-250uA	-100	7	-	V	
Gate Threshold Voltage	$V_{GS(th)}$	V _{DS} =V _{GS} , I _D =-250uA	-1	-2	-2.5	V	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-10V, I _D =-0.9A	-//	500	650		
		V _{GS} =-4.5V, I _D =-0.45A	/-	620	750	mΩ	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-80V, V _{GS} =0V		4-/	-1	uA	
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 20V, V _{DS} =0V	1 -		<u>+</u> 100	nA	
Dynamic (Note 7)							
Total Gate Charge	Q_g	V - 50V I - 4A	-/	8	-	nC	
Gate-Source Charge	Q_{gs}	V _{DS} =-50V, I _D =-1A,		1.8	-		
Gate-Drain Charge	Q_{gd}	VGS=-10V (Note 2,0)	-	1.4	7		
Input Capacitance	Ciss	\(- 45\(\) \(-0\(\)	s –	448	-	pF	
Output Capacitance	Coss	V _{DS} =-15V, V _{GS} =0V,	s .=	28	-		
Reverse Transfer Capacitance	Crss	f=1MHZ	<u>-</u>	21	-		
Turn-On Delay Time	td _(on)	\/_ F0\/ 4A	7 -	3.7	-	ns	
Turn-On Rise Time	tr	V _{DS} =-50V, I _D =1A,	- /	25	-		
Turn-Off Delay Time	td _(off)	V_{GS} =-10V, R_G =6.2 Ω	/-/	21	-		
Turn-Off Fall Time	tf	(1000 2,0)	/-	22	-		
Drain-Source Diode					200	10	
Maximum Continuous Drain-Source	l.		-	-	-1.5	А	
Diode Forward Current	Is						
Diode Forward Voltage	V _{SD}	I _S =-1A, V _{GS} =0V	-	-0.82	-1.2	V	



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Typical Electrical and Thermal Characteristics

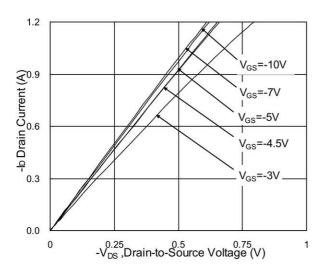


Fig.1 Typical Output Characteristics

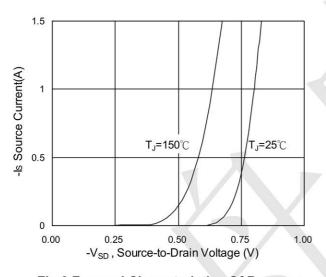


Fig.3 Forward Characteristics Of Reverse

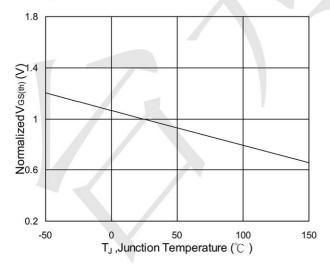


Fig.5 Normalized V_{GS(th)} vs. T_J

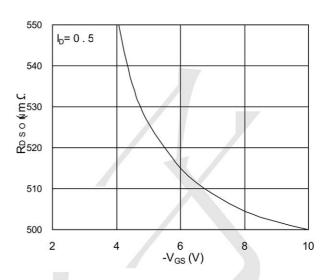


Fig.2 On-Resistance vs. Gate-Source

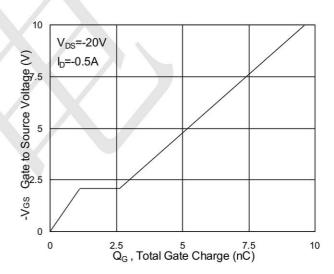


Fig.4 Gate-Charge Characteristics

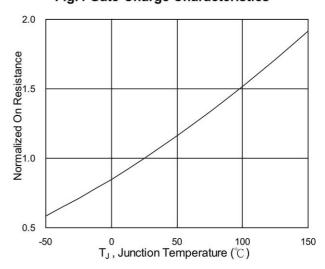
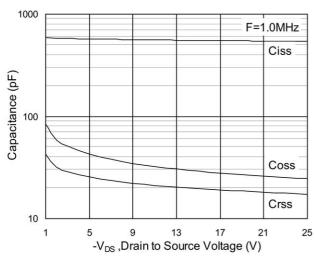


Fig.6 Normalized RDSON vs. TJ



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10.00 1ms 1.00 100ms -lo(A)0-1s **10S** 0.01 DC T_A=25°C Single Pulse 0.00 -V_{DS} (V) 0.1 100 1000

Fig.7 Capacitance

Fig.8 Safe Operating Area

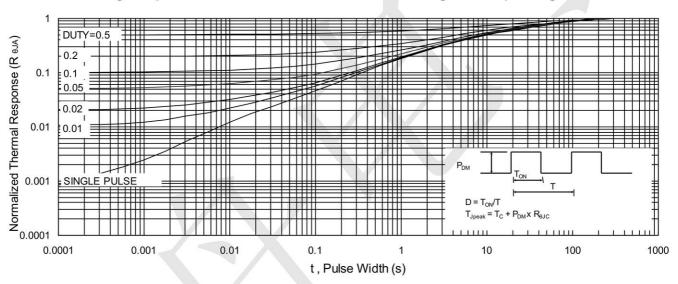
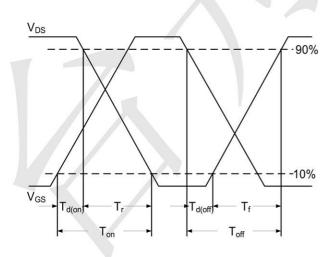


Fig.9 Normalized Maximum Transient Thermal Impedance



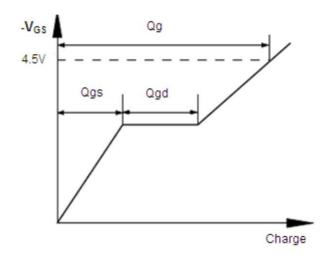


Fig.10 Switching Time Waveform

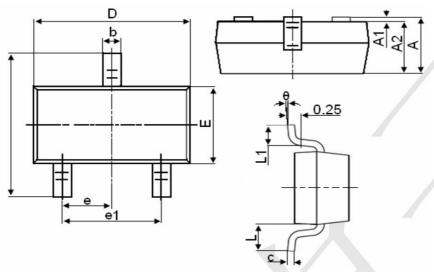
Fig.11 Gate Charge Waveform



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SOT-23 Package Information



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Symbol	Dimensions in Millimeters		
	MIN.	MAX.	
Α	0.900	1.150	
A1	0.000	0.100	
A2	0.900	1.050	
b	0.300	0.500	
С	0.080	0.150	
D	2.800	3.000	
E	1.200	1.400	
E1	2.250	2.550	
е		0.950TYP	
e1	1.800	2.000	
L	0.550REF		
L1	0.300	0.500	
θ	0°	8°	

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BSS340NWH6327XTSA1 MCM3400A-TP DMTH10H4M6SPS-13 IRF40SC240ARMA1 IPS60R1K0PFD7SAKMA1

IPS60R360PFD7SAKMA1 IPS60R600PFD7SAKMA1